

MOS FIELD EFFECT TRANSISTOR 2SK3404

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3404 is N-Channel MOS FET device that features a low on-state resistance and excellent switching characteristics, designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

★ ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3404	TO-220AB
2SK3404-ZK	TO-263(MP-25ZK)
2SK3404-ZJ	TO-263(MP-25ZJ)

FEATURES

- 4.5-V drive available
- · Low on-state resistance

RDS(on)1 = 14 m Ω MAX. (VGS = 10 V, ID = 20 A)

- · Low gate charge
 - $Q_G = 25 \text{ nC TYP.}$ ($I_D = 40 \text{ A}, V_{DD} = 24 \text{ V}, V_{GS} = 10 \text{ V}$)
- Built-in gate protection diode
- Surface mount device available

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Ves = 0 V)	VDSS	30	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±40	Α
Drain Current (Pulse) Note	ID(pulse)	±160	Α
Total Power Dissipation (T _A = 25°C)	P _{T1}	1.5	W
Total Power Dissipation (Tc = 25°C)	P _{T2}	40	W
Channel Temperature	Tch	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note PW \leq 10 μ s, Duty Cycle \leq 1%

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

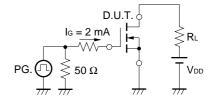


ELECTRICAL CHARACTERISTICS(TA = 25°C)

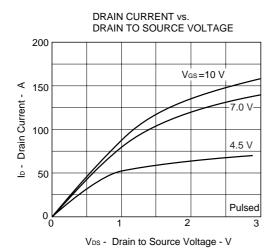
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Leakage Current	Ioss	Vps = 30 V, Vgs = 0 V			10	μΑ
Gate Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5		2.5	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 20 A	8.0			S
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, ID = 20 A		11	14	mΩ
	RDS(on)2	Vgs = 4.5 V, ID = 20 A		15	21	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		1400		pF
Output Capacitance	Coss	Vgs = 0 V		410		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		180		pF
Turn-on Delay Time	td(on)	V _{DD} = 15 V , I _D = 20 A		20		ns
Rise Time	tr	V _{GS(on)} = 10 V		9		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		50		ns
Fall Time	tf			14		ns
Total Gate Charge	Q _G	V _{DD} = 24 V		25		nC
Gate to Source Charge	Qgs	Vgs = 10 V		5.0		nC
Gate to Drain Charge	Q _{GD}	ID = 40 A		7.0		nC
Diode Forward Voltage	VF(S-D)	IF = 40 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 40 A, VGS = 0 V		31		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		28		nC

TEST CIRCUIT 1 SWITCHING TIME

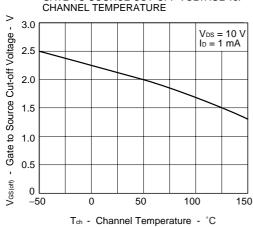
TEST CIRCUIT 2 GATE CHARGE



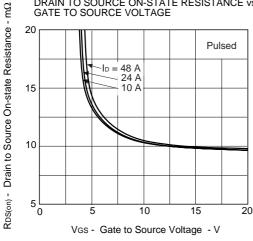
TYPICAL CHARACTERISTICS (TA = 25°C)



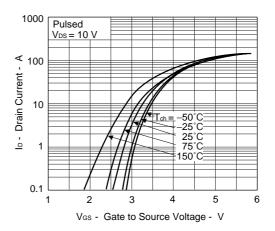




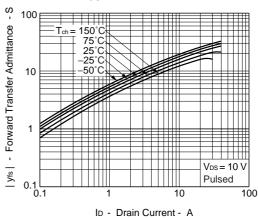
DRAIN TO SOURCE ON-STATE RESISTANCE vs.

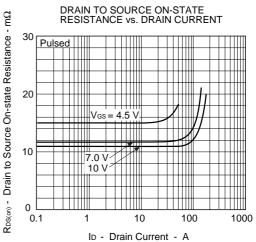


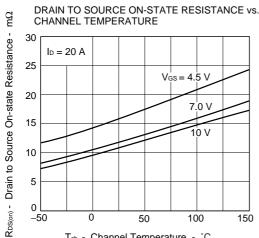
FORWARD TRANSFER CHARACTERISTICS

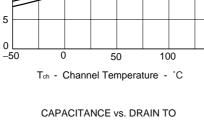


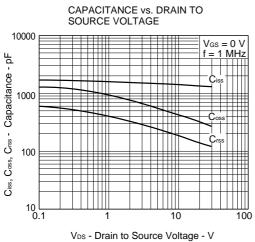
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

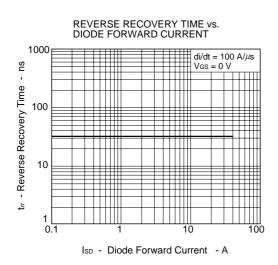


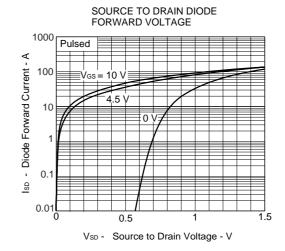


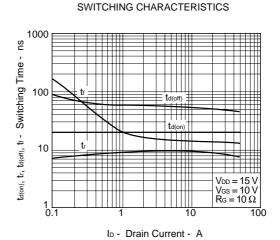


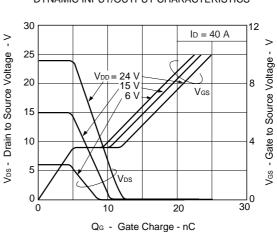


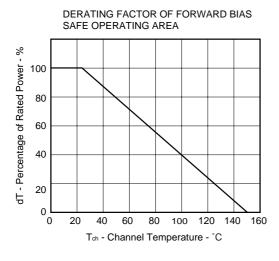


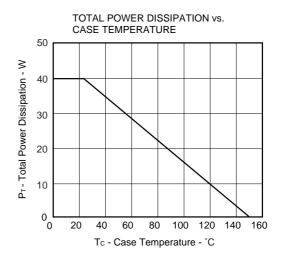




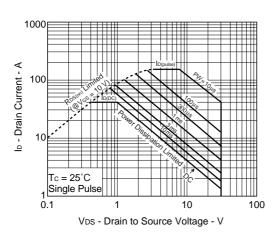


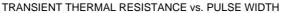


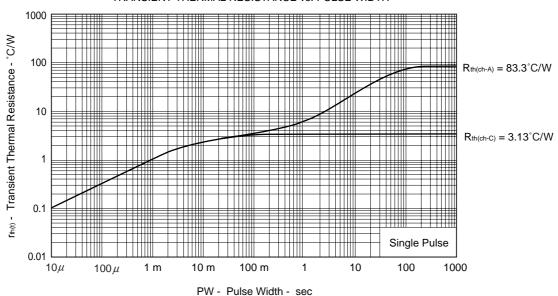




FORWARD BIAS SAFE OPERATING AREA



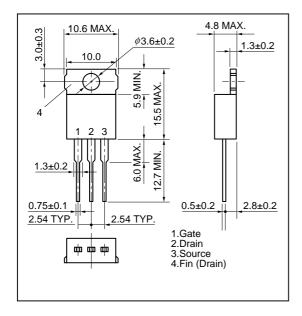




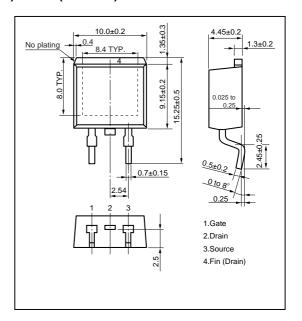
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PACKAGE DRAWINGS (Unit: mm)

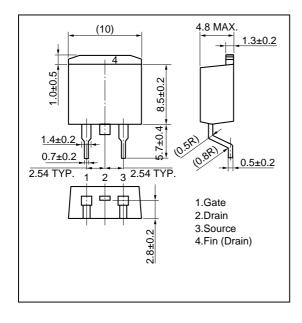
1)TO-220AB (MP-25)



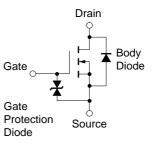
★ 2)TO-263 (MP-25ZK)



3)TO-263 (MP-25ZJ)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

2SK3404



[MEMO]

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